

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)}$	I_D $T_A = +25^\circ C$
25V	4Ω @ $V_{GS} = 4.5V$	0.32A
	5Ω @ $V_{GS} = 2.7V$	0.28A

Description

This MOSFET has been designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Load switch
- Portable applications
- Power Management Functions

Features

- 0.4mm ultra low profile package for thin application
- 0.48mm² package footprint, 16 times smaller than SOT23
- Low $V_{GS(th)}$, can be driven directly from a battery
- Low $R_{DS(on)}$
- ESD Protected Gate (>6kV Human Body Mode)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

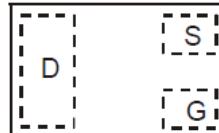
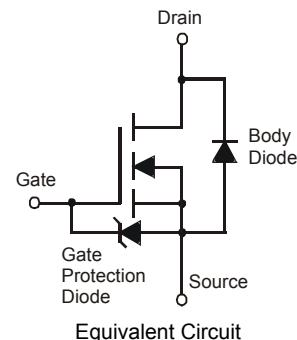
- Case: X2-DFN0806-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208 (e4)
- Weight: 0.00043 grams (approximate)



X2-DFN0806-3



Bottom View

Top View
Package Pin Configuration

Equivalent Circuit

Ordering Information (Note 4)

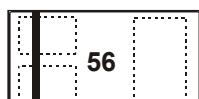
Part Number	Compliance	Case	Packaging
DMN25D0UFA-7B	Standard	X2-DFN0806-3	10,000/Tape & Reel

Notes:

- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information

DMN25D0UFA-7B



56 = Product Type Marking Code

Top View
Bar Denotes Gate
and Source Side

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	25	V
Gate-Source Voltage	V_{GSS}	8	
Continuous Drain Current, $V_{GS} = 4.5\text{V}$	(Note 6)	0.32	A
	I_D	0.25	
	(Note 5)	0.24	A
Pulsed Drain Current	(Note 7)	I_{DM}	1.2
			A

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	(Note 6)	0.63	W
	(Note 5)	0.28	
Thermal Resistance, Junction to Ambient	(Note 6)	201	°C/W
	(Note 5)	338	
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV_{DSS}	25	—	—	V	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$
Zero Gate Voltage Drain Current	I_{DSS}	—	—	1	μA	$V_{DS} = 20\text{V}, V_{GS} = 0\text{V}$
Gate-Source Leakage	I_{GSS}	—	—	100	nA	$V_{GS} = 8\text{V}, V_{DS} = 0\text{V}$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	$V_{GS(\text{th})}$	0.6	—	1.2	V	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$
Static Drain-Source On-Resistance	$R_{DS(\text{on})}$	—	—	4	Ω	$V_{GS} = 4.5\text{V}, I_D = 0.4\text{A}$
		—	—	5		$V_{GS} = 2.7\text{V}, I_D = 0.2\text{A}$
Forward Transfer Admittance	$ Y_{fs} $	—	1	-	S	$V_{DS} = 5\text{V}, I_D = 0.4\text{A}$
Diode Forward Voltage	V_{SD}	—	0.76	1.2	V	$V_{GS} = 0\text{V}, I_S = 0.29\text{A}$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C_{iss}	—	27.9	—	pF	$V_{DS} = 10\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$
Output Capacitance	C_{oss}	—	6.1	—	pF	
Reverse Transfer Capacitance	C_{rss}	—	2	—	pF	
Gate Resistance	R_g	—	26.4	—	Ω	$V_{DS} = 0\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$
Total Gate Charge	Q_g	—	0.36	—	nC	$V_{DS} = 5\text{V}, V_{GS} = 4.5\text{V}, I_D = 0.2\text{A}$
Gate-Source Charge	Q_{gs}	—	0.06	—	nC	
Gate-Drain Charge	Q_{gd}	—	0.04	—	nC	
Turn-On Delay Time	$t_{D(\text{on})}$	—	2.9	—	ns	$V_{DS} = 6\text{V}, V_{GS} = 4.5\text{V}, I_D = 0.5\text{A}, R_G = 50\Omega$
Turn-On Rise Time	t_r	—	1.8	—	ns	
Turn-Off Delay Time	$t_{D(\text{off})}$	—	6.6	—	ns	
Turn-Off Fall Time	t_f	—	2.3	—	ns	

Notes:

5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
6. Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to production testing.

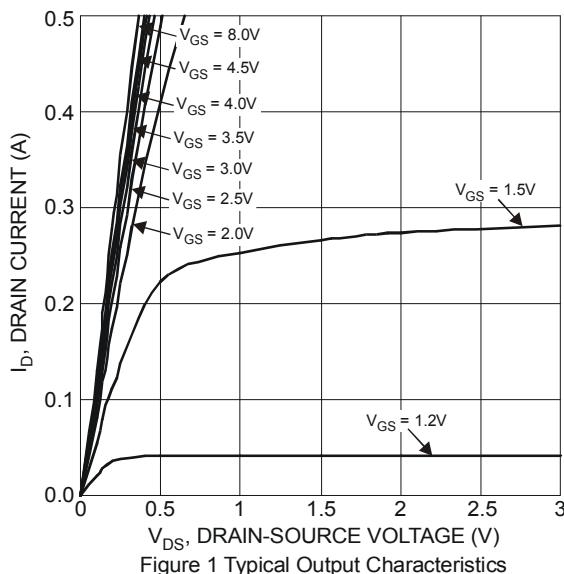


Figure 1 Typical Output Characteristics

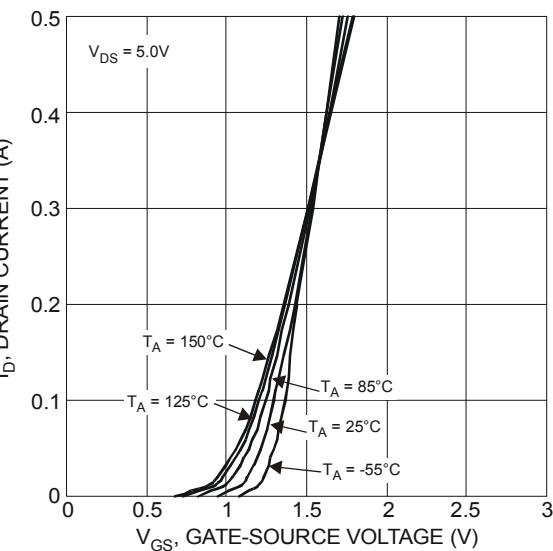


Figure 2 Typical Transfer Characteristics

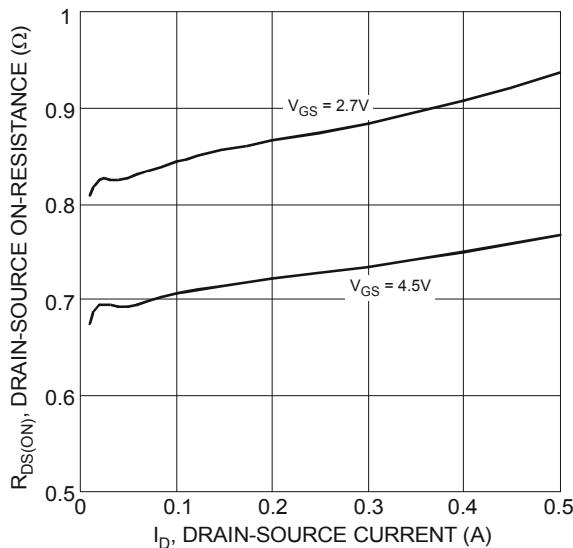


Figure 3 Typical On-Resistance vs.
Drain Current and Gate Voltage

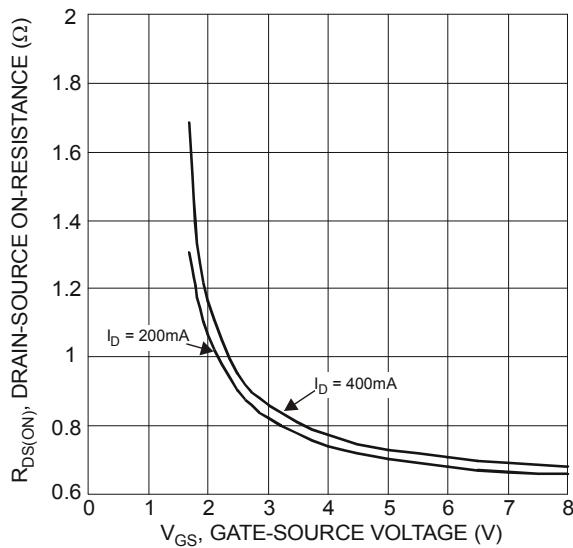


Figure 4 Typical Transfer Characteristics

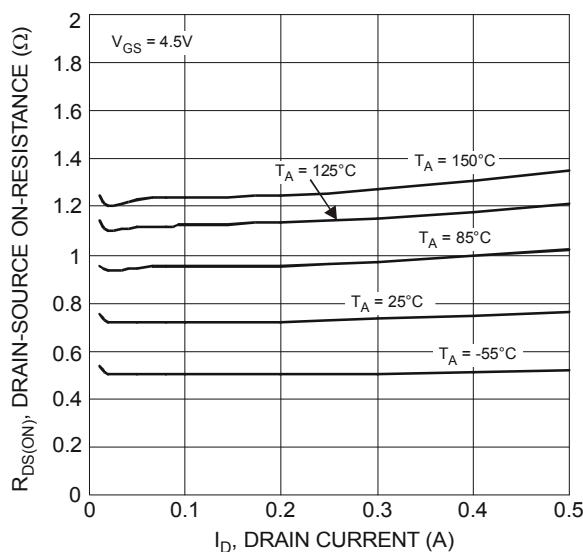


Figure 5 Typical On-Resistance vs.
Drain Current and Temperature

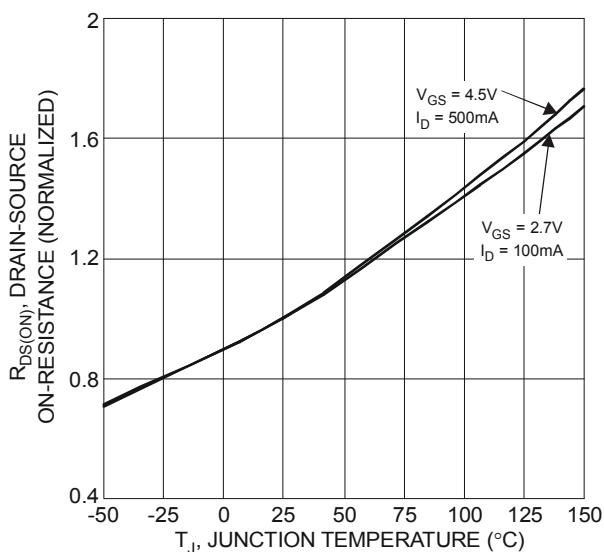
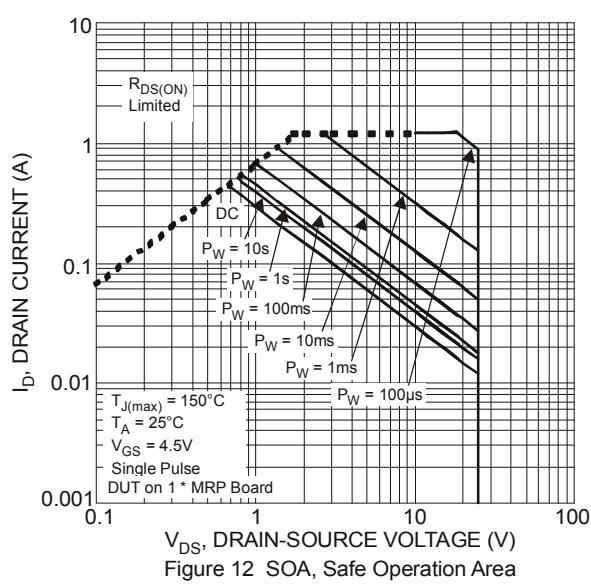
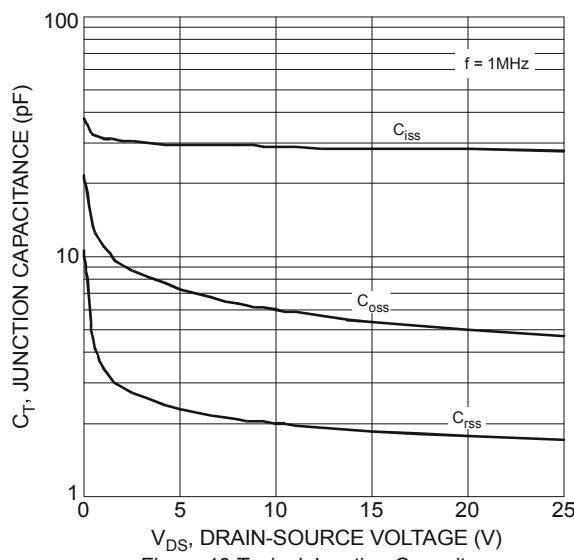
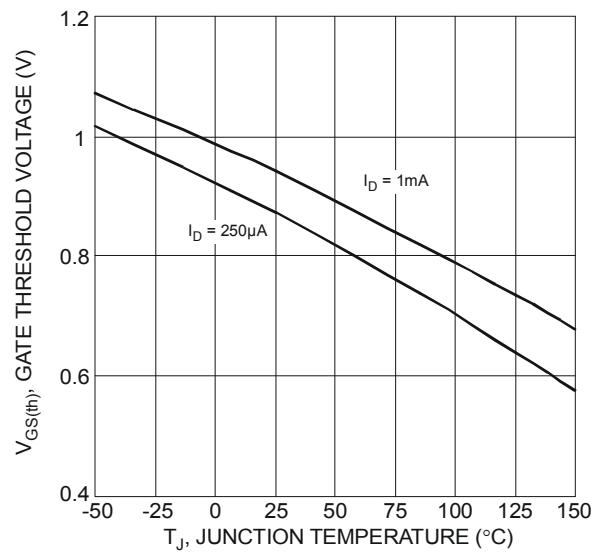
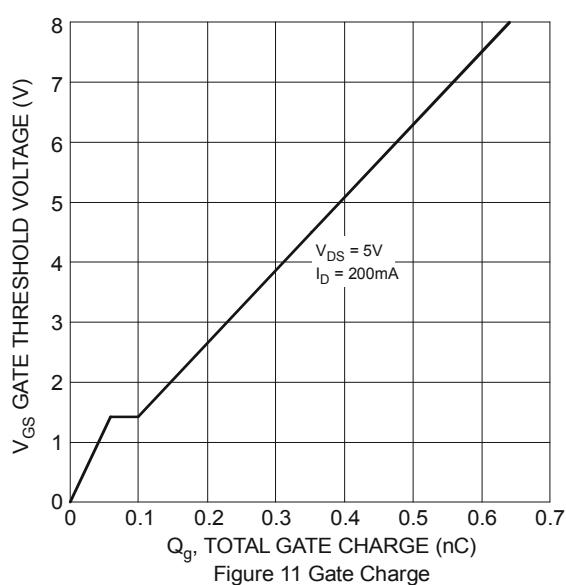
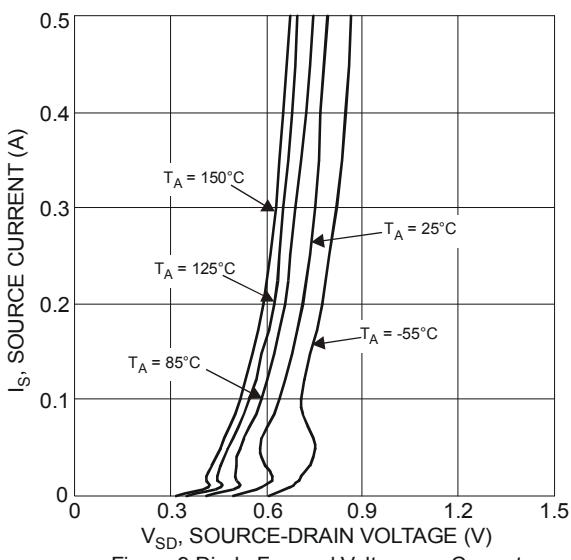
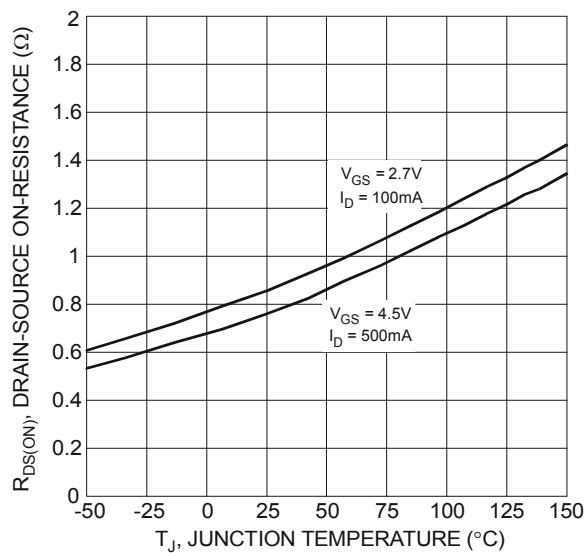
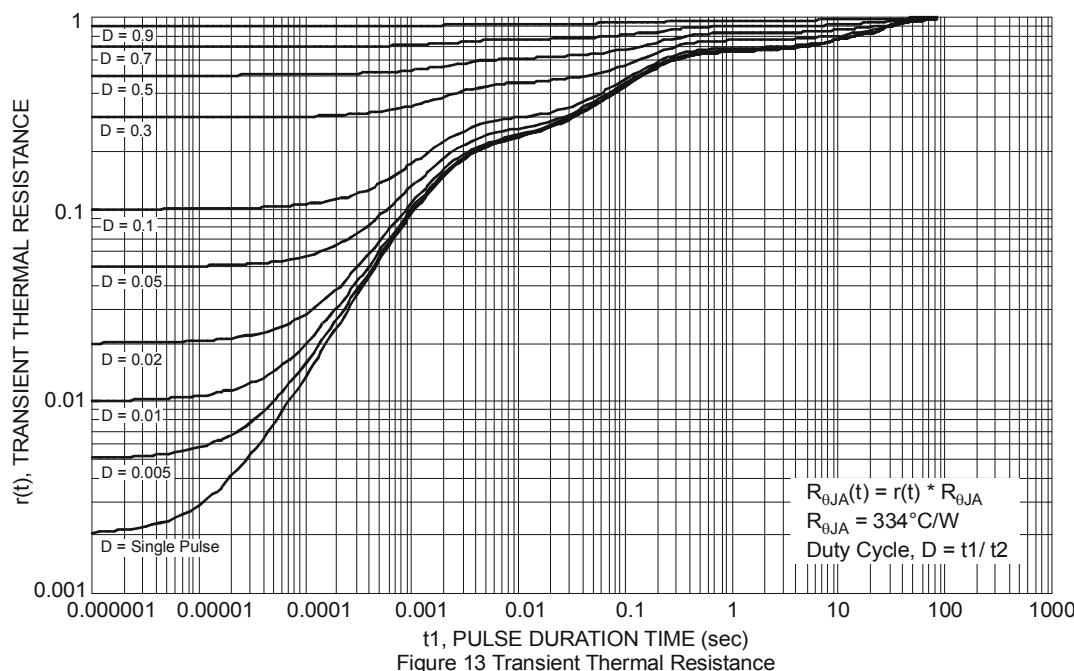


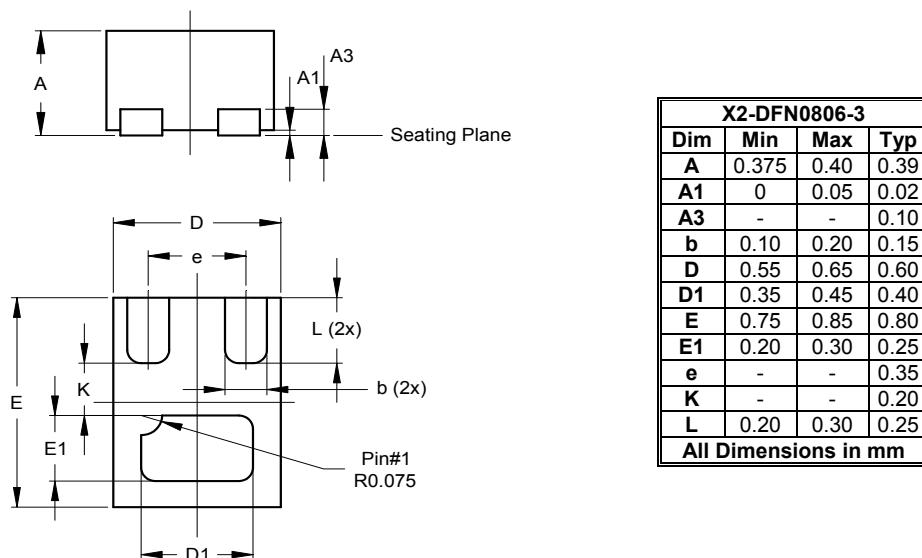
Figure 6 On-Resistance Variation with Temperature





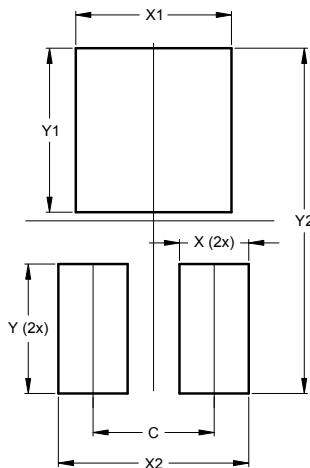
Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	0.350
X	0.200
X1	0.450
X2	0.550
Y	0.375
Y1	0.475
Y2	1.000

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